







2N5020, 2N5021 P-Channel JFET

Features

- InterFET P0032F Geometry
- Typical Noise: 10 nV/vHz
- · Low Ciss: 3.2pF Typical
- RoHS Compliant
- SMT, TH, and Bare Die Package options.

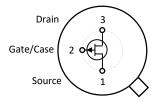
Applications

- · Analog Switches
- Choppers

Description

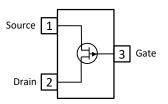
The 25V InterFET 2N5020 and 2N5021 are targeted for data switches and low-level chopper designs. Gate leakages are typically less than 1nA at room temperatures. The TO-18 package is hermetically sealed and suitable for military applications.

TO-18 Bottom View



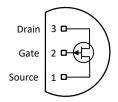


SOT23 Top View





TO-92 Bottom View





Product Summary

Parameters		2N5020 Min	2N5021 Min	Unit
BV _{GSS}	Gate to Source Breakdown Voltage	25	25	V
I _{DSS}	Drain to Source Saturation Current	-0.3	-1	mA
V _{GS(off)}	Gate to Source Cutoff Voltage	0.3	0.5	V
G _{FS}	Forward Transconductance	1000	1500	μS

Ordering Information Custom Part and Binning Options Available

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Part Number	Description	Case	Packaging		
2N5020; 2N5021	Through-Hole	TO-18	Bulk		
PN5020; PN5021	Through-Hole	TO-92	Bulk		
SMP5020; SMP5021	Surface Mount	SOT23	Bulk		
	7" Tape and Reel: Max 3,000 Pieces		Minimum 1,000 Pieces		
SMP5020TR; SMP5021TR	13" Tape and Reel: Max 9,000 Pieces	SOT23	Tape and Reel		
2N5020COT; 2N5021COT	Chip Orientated Tray (COT Waffle Pack)	СОТ	400/Waffle Pack		
2N5020CFT; 2N5021CFT	Chip Face-up Tray (CFT Waffle Pack)	CFT	400/Waffle Pack		



Disclaimer: It is the Buyers responsibility for designing, validating and testing the end application under all field use cases and extreme use conditions. Guaranteeing the application meets required standards, regulatory compliance, and all safety and security requirements is the responsibility of the Buyer. These resources are subject to change without notice.









Electrical Characteristics

Maximum Ratings (@ T_A = 25°C, Unless otherwise specified)

	Parameters	Value	Unit
V_{RGS}	Reverse Gate Source and Gate Drain Voltage	-25	V
I _{FG}	Continuous Forward Gate Current	50	mA
PD	Continuous Device Power Dissipation	500	mW
Р	Power Derating	4	mW/°C
Τı	Operating Junction Temperature	-55 to 125	°C
T _{STG}	Storage Temperature	-65 to 200	°C

Static Characteristics (@ TA = 25°C, Unless otherwise specified)

			2N5020		2N5021		
	Parameters	Conditions	Min	Max	Min	Max	Unit
V _{(BR)GSS}	Gate to Source Breakdown Voltage	$V_{DS} = 0V$, $I_G = 1\mu A$	25		25		V
I _{GSS}	Gate to Source Reverse Current	V _{GS} = 15V, V _{DS} = 0V		1		1	nA
V _{GS(OFF)}	Gate to Source Cutoff Voltage	$V_{DS} = -15V, I_D = 1nA$	0.3	1.5	0.5	2.5	V
I _{DSS}	Drain to Source Saturation Current	$V_{GS} = 0V$, $V_{DS} = -15V$ (Pulsed)	-0.3	-1.2	-1	-3.5	mA

Dynamic Characteristics (@ TA = 25°C, Unless otherwise specified)

			2N5020		2N5021		
	Parameters	Conditions	Min	Max	Min	Max	Unit
GFS	Forward Transconductance	V _{DS} = -15V, V _{GS} = 0V, f = 1kHz	1000	3500	1500	6000	μS
Gos	Output Conductance	V _{DS} = -15V, V _{GS} = 0V, f = 1kHz		20		20	μS
Ciss	Input Capacitance	V _{DS} = -15V, V _{GS} = 0V, f = 1MHz		25		25	pF
Crss	Reverse Transfer Capacitance	V _{DS} = -15V, V _{GS} = 0V, f = 1MHz		7		7	pF



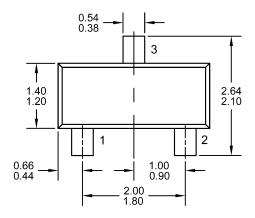


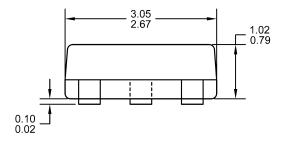


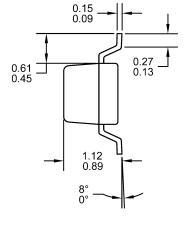


SOT23 (TO-236AB) Mechanical and Layout Data

Package Outline Data

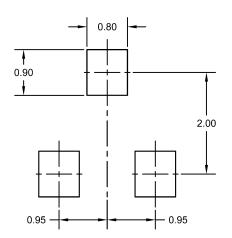






- 1. All linear dimensions are in millimeters.
- 2. Package weight approximately 0.12 grams
- 3. Molded plastic case UL 94V-0 rated
- For Tape and Reel specifications refer to InterFET CTC-021 Tape and Reel Specification, Document number: IF39002
- Bulk product is shipped in standard ESD shipping material
- 6. Refer to JEDEC standards for additional information.

Suggested Pad Layout



- 1. All linear dimensions are in millimeters.
- The suggested land pattern dimensions have been provided for reference only. A more robust pattern may be desired for wave soldering.



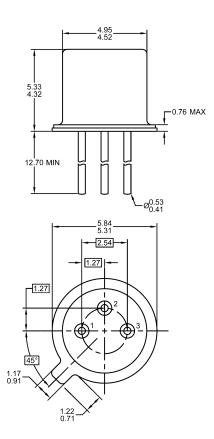






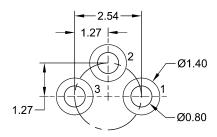
TO-18 Mechanical and Layout Data

Package Outline Data



- 1. All linear dimensions are in millimeters.
- 2. Package weight approximately 0.29 grams
- Bulk product is shipped in standard ESD shipping material
- 4. Refer to JEDEC standards for additional information.

Suggested Through-Hole Layout



- 1. All linear dimensions are in millimeters.
- The suggested land pattern dimensions have been provided as a straight lead reference only. A more robust pattern may be desired for wave soldering and/or bent lead configurations.



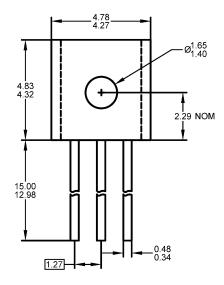


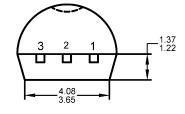


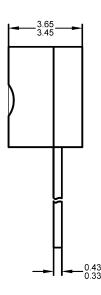


TO-92 Mechanical and Layout Data

Package Outline Data

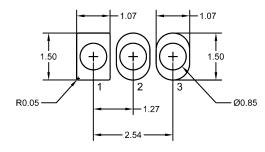






- 1. All linear dimensions are in millimeters.
- 2. Package weight approximately 0.19 grams
- 3. Molded plastic case UL 94V-0 rated
- Bulk product is shipped in standard ESD shipping material
- 5. Refer to JEDEC standards for additional information.

Suggested Through-Hole Layout



- 1. All linear dimensions are in millimeters.
- The suggested land pattern dimensions have been provided as a straight lead reference only. A more robust pattern may be desired for wave soldering and/or bent lead configurations.